

Supplementary Information

Electrically and Thermally Stable Gate Dielectrics from Thiol-Ene Cross-Linked Systems for Use in Organic Thin-Film Transistors

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Additional Figures

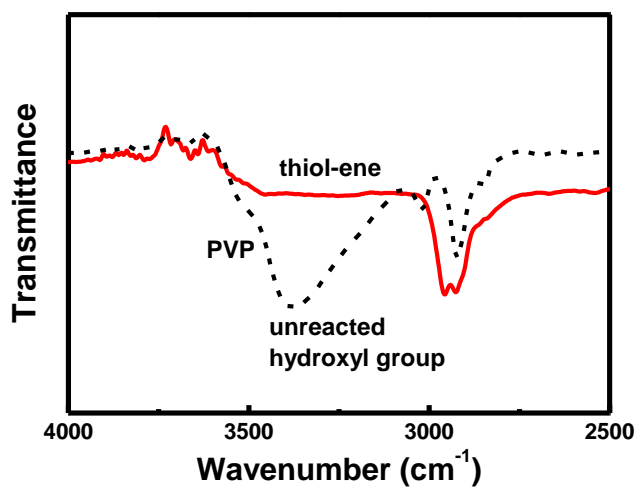


Figure S1. FT-IR spectra of the thiol-ene and PVP films.

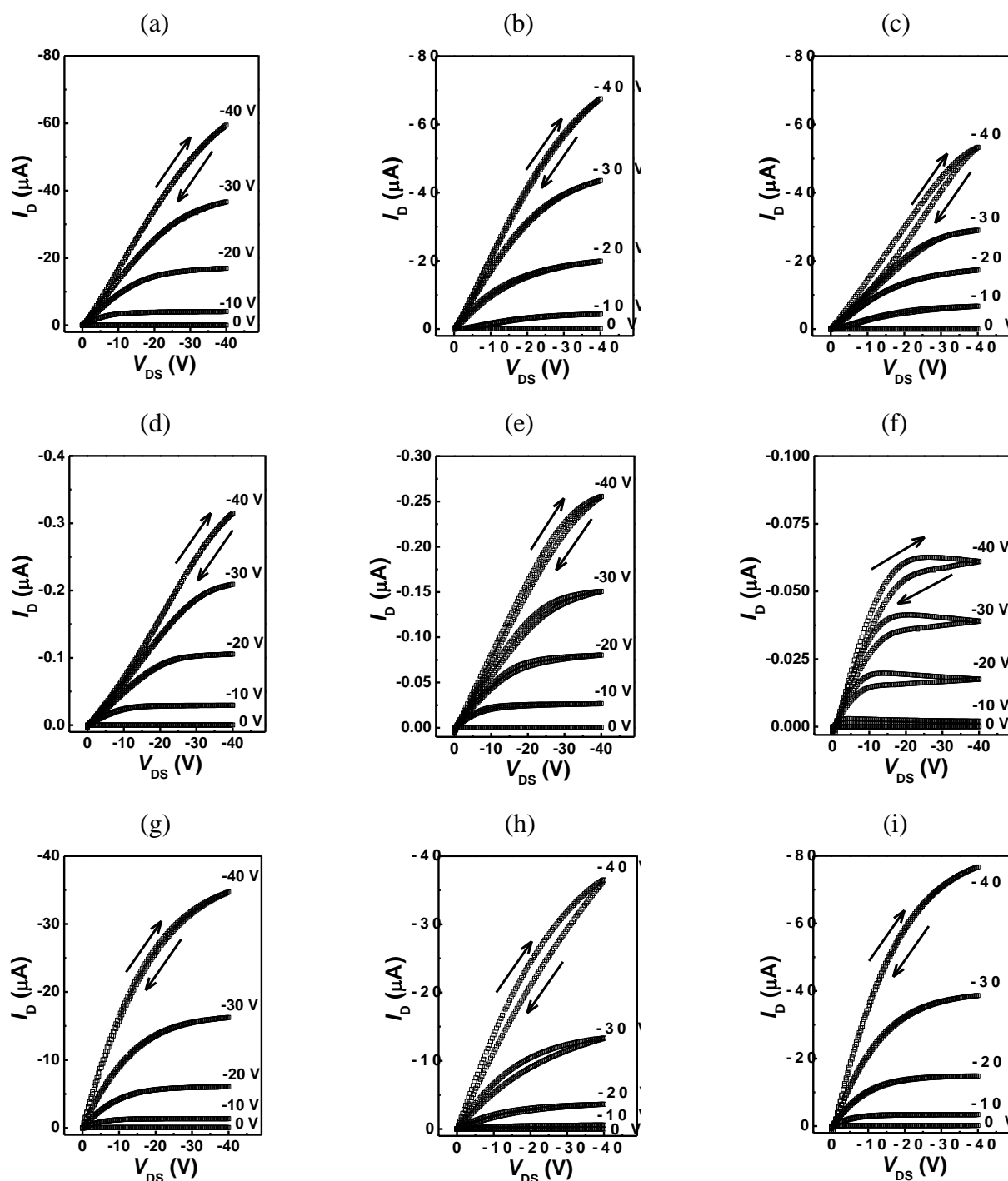


Figure S2. The output characteristics of OTFTs by inkjet printing of a mixture of TIPS pentacene and APC on (a) thiol-ene, (b) PVP, and (c) SiO₂, by spin coating of TIPS pentacene on (d) thiol-ene, (e) PVP, and (f) SiO₂, and by thermal evaporation of pentacene on (g) thiol-ene, (h) PVP, and (i) SiO₂.

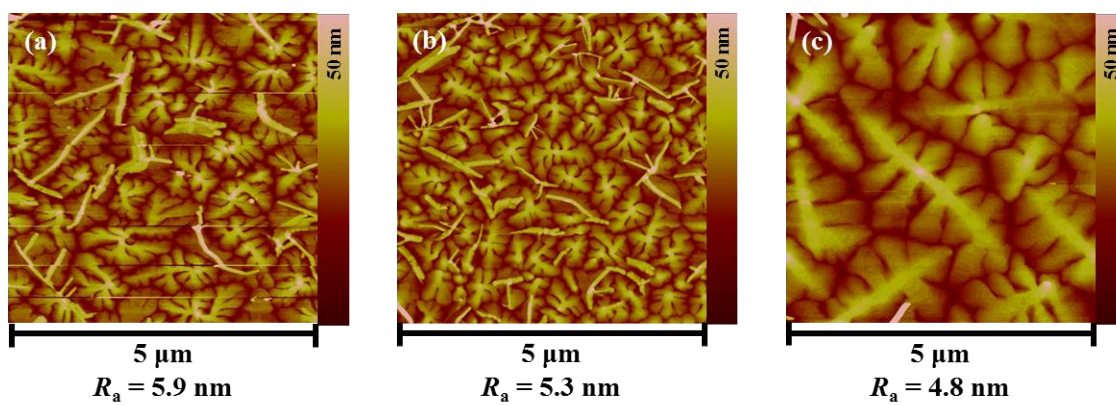


Figure S3. AFM images of deposited pentacene crystals on (a) thiol-ene, (b) PVP, and (c) SiO_2 .